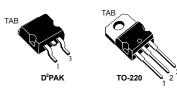
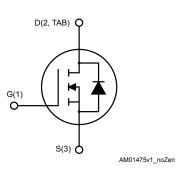


## Datasheet

# N-channel 600 V, 0.4 Ω typ., 11 A, MDmesh™ II Power MOSFETs in D²PAK and TO-220 packages





## **Features**

| Order codes | V <sub>DSS</sub><br>(@ T <sub>Jmax</sub> ) | R <sub>DS(on)</sub> max. | Ι <sub>D</sub> | Package            |
|-------------|--|--------------------------|----------------|--------------------|
| STB11NM60T4 | 650 V 0.45 Ω                               | 0.45.0                   | 11 A           | D <sup>2</sup> PAK |
| STP11NM60   |  |                          | TO-220         |                    |

• 100% avalanche tested

- Low input capacitance and gate charge
- Low gate input resistance

## **Applications**

Switching applications

# Description

These devices are N-channel Power MOSFETs developed using the second generation of MDmesh<sup>™</sup> technology. These revolutionary Power MOSFETs associate a vertical structure to the company's strip layout to yield one of the world's lowest on-resistance and gate charge. They are therefore suitable for the most demanding high-efficiency converters.

| Product status link        |               |  |  |  |
|----------------------------|---------------|--|--|--|
| STB11NM60T4                |               |  |  |  |
| STP11NM60                  |               |  |  |  |
|                            |               |  |  |  |
| Product                    | summary       |  |  |  |
| Order code                 | STB11NM60T4   |  |  |  |
| Marking                    | B11NM60       |  |  |  |
| Package D <sup>2</sup> PAK |               |  |  |  |
| Packing                    | Tape and reel |  |  |  |
|                            |               |  |  |  |

Order code Marking

Package

Packing

STP11NM60

P11NM60 TO-220

Tube



# 1 Electrical ratings

| Symbol                         | Parameter   | Value      | Unit |
|--------------------------------|---|------------|------|
| V <sub>DS</sub>                | Gate-source voltage                                   | 600        | V    |
| V <sub>GS</sub>                | Gate- source voltage                                  | ±30        | V    |
| ۱ <sub>D</sub>                 | Drain current (continuous) at $T_C$ = 25 °C           | 11         | А    |
| ۱ <sub>D</sub>                 | Drain current (continuous) at T <sub>C</sub> = 100 °C | 7          | A    |
| I <sub>DM</sub> <sup>(1)</sup> | Drain current (pulsed)                                | 44         | А    |
| P <sub>TOT</sub>               | Total dissipation at $T_C$ = 25 °C                    | 160        | W    |
| dv/dt <sup>(2)</sup>           | Peak diode recovery voltage slope                     | 15         | V/ns |
| T <sub>stg</sub>               | Storage temperature range                             | -65 to 150 | °C   |
| Тj                             | T <sub>j</sub> Operating junction temperature range   |            |      |

#### Table 1. Absolute maximum ratings

1. Pulse width limited by safe operating area.

2.  $I_{SD} \leq 11$  A,  $di/dt \leq 400$  A/ $\mu$ s,  $V_{DD} \leq V_{(BR)DSS}$ ,  $T_j \leq T_{JMAX}$ .

## Table 2. Thermal data

| Symbol                              | Parameter                           | Va                 | Unit   |      |  |
|-------------------------------------|-------------------------------------|--------------------|--------|------|--|
| Symbol                              | Falameter                           | D <sup>2</sup> PAK | TO-220 | Unit |  |
| R <sub>thj-case</sub>               | Thermal resistance junction-case    | 0.                 |        |      |  |
| R <sub>thj-amb</sub>                | Thermal resistance junction-ambient | 62.5               |        |      |  |
| R <sub>thj-pcb</sub> <sup>(1)</sup> | Thermal resistance junction-pcb     | 35                 |        |      |  |

1. When mounted on 1inch<sup>2</sup> FR-4 board, 2 oz Cu.

#### Table 3. Avalanche characteristics

| Symbol          | Parameter  | Value | Unit |
|-----------------|--|-------|------|
| I <sub>AR</sub> | Avalanche current, repetitive or non-repetitive (pulse width limited by ${\rm T}_{\rm jmax})$                              | 5.5   | А    |
| E <sub>AS</sub> | Single pulse avalanche energy (starting T <sub>j</sub> = 25 °C, I <sub>D</sub> = I <sub>AR</sub> , V <sub>DD</sub> = 50 V) | 350   | mJ   |



# 2 Electrical characteristics

(T<sub>C</sub> = 25 °C unless otherwise specified).

| Symbol               | Parameter  | Test conditions   | Min. | Тур. | Max. | Unit |
|----------------------|--|---|------|------|------|------|
| V <sub>(BR)DSS</sub> | Drain-source breakdown voltage                   | $V_{GS}$ = 0 V, I <sub>D</sub> = 250 $\mu$ A                                | 600  |      |      | V    |
|                      |  | $V_{GS}$ = 0 V, $V_{DS}$ = 600 V  |      |      | 1    | μA   |
| I <sub>DSS</sub>     | I <sub>DSS</sub> Zero gate voltage drain current | $V_{GS}$ = 0 V, $V_{DS}$ = 600 V,<br>T <sub>C</sub> = 125 °C <sup>(1)</sup> |      |      | 10   | μA   |
| I <sub>GSS</sub>     | Gate-body leakage current                        | $V_{DS}$ = 0 V, $V_{GS}$ = ±30 V  |      |      | ±100 | nA   |
| V <sub>GS(th)</sub>  | Gate threshold voltage                           | $V_{DS}$ = $V_{GS}$ , $I_D$ = 250 $\mu$ A                                   | 3    | 4    | 5    | V    |
| R <sub>DS(on)</sub>  | Static drain-source on-resistance                | V <sub>GS</sub> = 10 V, I <sub>D</sub> = 5.5 A                              |      | 0.4  | 0.45 | Ω    |

#### Table 4. On/off states

1. Defined by design, not subject to production test.

## Table 5. Dynamic

| Symbol                              | Parameter                     | Test conditions  | Min. | Тур. | Max. | Unit |
|-------------------------------------|-------------------------------|--|------|------|------|------|
| C <sub>iss</sub>                    | Input capacitance             |  | -    | 1000 | -    | pF   |
| C <sub>oss</sub>                    | Output capacitance            | $V_{DS}$ = 25 V, f = 1 MHz, $V_{GS}$ = 0 V             | -    | 230  | -    | pF   |
| C <sub>rss</sub>                    | Reverse transfer capacitance  |  | -    | 25   | -    | pF   |
| C <sub>oss eq.</sub> <sup>(1)</sup> | Equivalent output capacitance | $V_{DS}$ = 0 V to 480 V, $V_{GS}$ = 0 V                | -    | 100  | -    | pF   |
| R <sub>G</sub>                      | Intrinsic gate resistance     | f = 1 MHz open drain                                   | -    | 1.6  | -    | Ω    |
| Qg                                  | Total gate charge             | V <sub>DD</sub> = 480 V, I <sub>D</sub> = 11 A,        | -    | 30   | -    | nC   |
| Q <sub>gs</sub>                     | Gate-source charge            | V <sub>GS</sub> = 0 to 10 V                            | -    | 10   | -    | nC   |
| Q <sub>gd</sub>                     | Gate-drain charge             | (see Figure 12. Test circuit for gate charge behavior) | -    | 15   | -    | nC   |

 C<sub>oss eq.</sub> is defined as a constant equivalent capacitance giving the same charging time as C<sub>oss</sub> when V<sub>DS</sub> increases from 0 to 80% V<sub>DSS</sub>

| Symbol               | Parameter             | Test conditions  | Min. | Тур. | Max. | Unit |
|----------------------|-----------------------|--|------|------|------|------|
| t <sub>d(on)</sub>   | Turn-on delay time    | $V_{DD}$ = 300 V, I <sub>D</sub> = 5.5 A,  | -    | 20   | -    | ns   |
| tr                   | Rise time             | $R_G$ = 4.7 $\Omega$ , $V_{GS}$ = 10 V<br>(see Figure 11. Test circuit for<br>resistive load switching times and<br>Figure 16. Switching time<br>waveform) | _    | 20   | -    | ns   |
| t <sub>r(Voff)</sub> | Off-voltage rise time | V <sub>DD</sub> = 480 V, I <sub>D</sub> = 11 A,  | -    | 6    | -    | ns   |
| t <sub>f</sub>       | Fall time             | $R_G = 4.7 \Omega$ , $V_{GS} = 10 V$ (see  | -    | 11   | -    | ns   |
| t <sub>c</sub>       | Cross-over time       | Figure 13. Test circuit for inductive<br>load switching and diode recovery<br>times and Figure 16. Switching<br>time waveform)                             | -    | 19   | -    | ns   |

#### Table 6. Switching times

5.7

20

-

\_

Unit

А

А

V ns μC

А

ns

μC

А

| Symbol                          | Parameter                     | Test conditions   | Min. | Тур. | Max. |
|---------------------------------|-------------------------------|---|------|------|------|
| I <sub>SD</sub>                 | Source-drain current          |   | -    |      | 11   |
| I <sub>SDM</sub> <sup>(1)</sup> | Source-drain current (pulsed) |   | -    |      | 44   |
| V <sub>SD</sub> <sup>(2)</sup>  | Forward on voltage            | $V_{GS}$ = 0 V, I <sub>SD</sub> = 11 A  | -    |      | 1.5  |
| t <sub>rr</sub>                 | Reverse recovery time         | I <sub>SD</sub> = 11 A, di/dt = 100 A/µs,   | -    | 390  |      |
| Q <sub>rr</sub>                 | Reverse recovery charge       | V <sub>DD</sub> = 100 V   | -    | 3.8  |      |
| I <sub>RRM</sub>                | Reverse recovery current      | (see Figure 13. Test circuit for inductive load switching and diode recovery times) | -    | 19.5 |      |
| t <sub>rr</sub>                 | Reverse recovery time         | I <sub>SD</sub> = 11 A, di/dt = 100 A/µs,   | -    | 570  |      |

 $V_{DD}$  = 100 V, T<sub>j</sub> = 150 °C

recovery times)

(see Figure 13. Test circuit for inductive load switching and diode

#### Table 7. Source drain diode

1. Pulse width is limited by safe operating area

Qrr

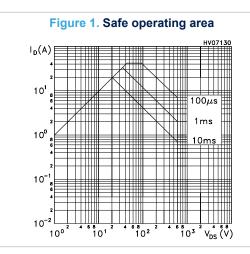
I<sub>RRM</sub>

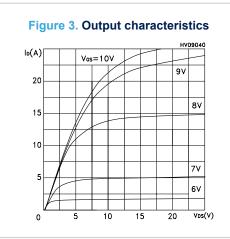
2. Pulse test: pulse duration =  $300 \ \mu$ s, duty cycle 1.5%

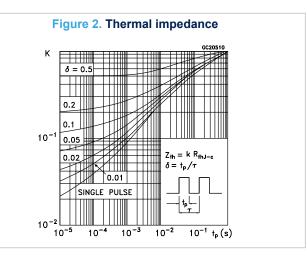
Reverse recovery charge

Reverse recovery current

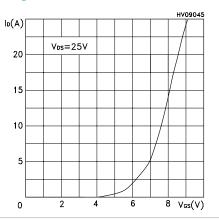
# 2.1 Electrical characteristics (curves)

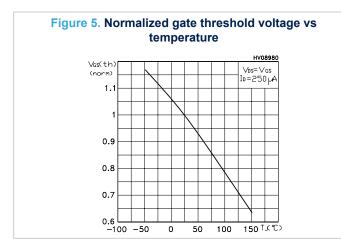




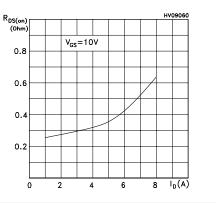


## Figure 4. Transfer characteristics

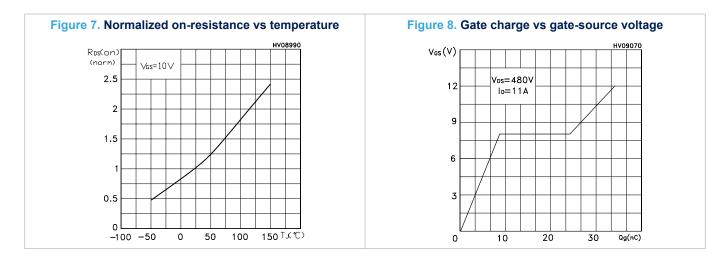


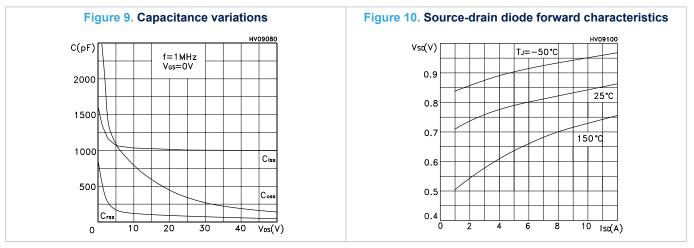






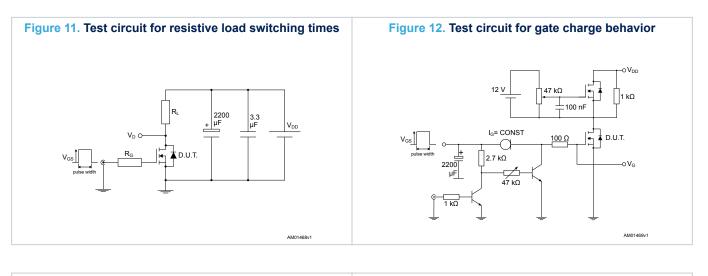


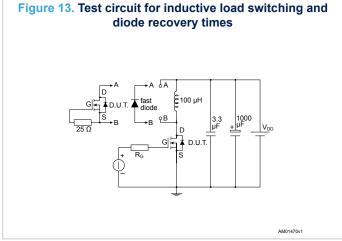


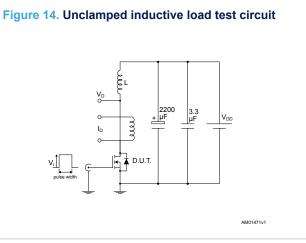


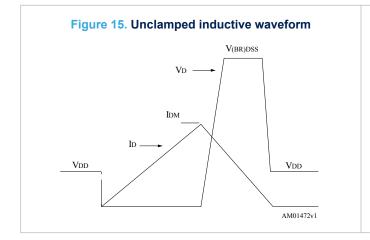


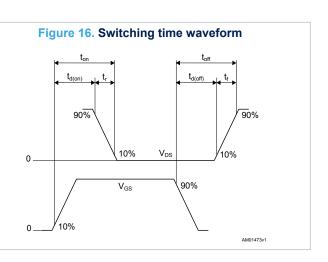
# 3 Test circuits









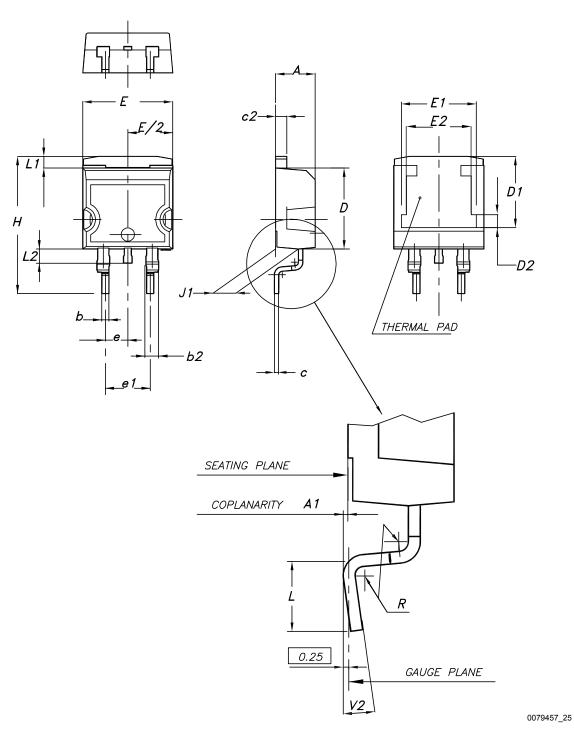


# 4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: www.st.com. ECOPACK<sup>®</sup> is an ST trademark.

# 4.1 D<sup>2</sup>PAK (TO-263) type A package information

## Figure 17. D<sup>2</sup>PAK (TO-263) type A package outline

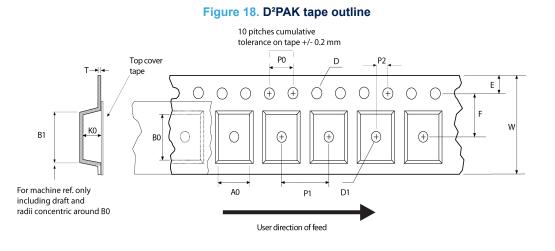


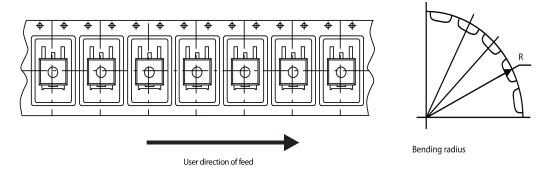
| Dim. |       | mm   |       |
|------|-------|------|-------|
| Dim. | Min.  | Тур. | Max.  |
| A    | 4.40  |      | 4.60  |
| A1   | 0.03  |      | 0.23  |
| b    | 0.70  |      | 0.93  |
| b2   | 1.14  |      | 1.70  |
| С    | 0.45  |      | 0.60  |
| c2   | 1.23  |      | 1.36  |
| D    | 8.95  |      | 9.35  |
| D1   | 7.50  | 7.75 | 8.00  |
| D2   | 1.10  | 1.30 | 1.50  |
| E    | 10.00 |      | 10.40 |
| E1   | 8.30  | 8.50 | 8.70  |
| E2   | 6.85  | 7.05 | 7.25  |
| е    |       | 2.54 |       |
| e1   | 4.88  |      | 5.28  |
| Н    | 15.00 |      | 15.85 |
| J1   | 2.49  |      | 2.69  |
| L    | 2.29  |      | 2.79  |
| L1   | 1.27  |      | 1.40  |
| L2   | 1.30  |      | 1.75  |
| R    |       | 0.40 |       |
| V2   | 0°    |      | 8°    |

## Table 8. D<sup>2</sup>PAK (TO-263) type A package mechanical data

# 4.2 D<sup>2</sup>PAK packing information

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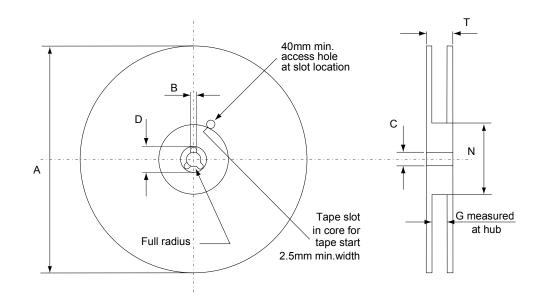




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DS3653 - Rev 7 Downloaded from Arrow.com.

## Figure 19. D<sup>2</sup>PAK reel outline



AM06038v1

## Table 9. D<sup>2</sup>PAK tape and reel mechanical data

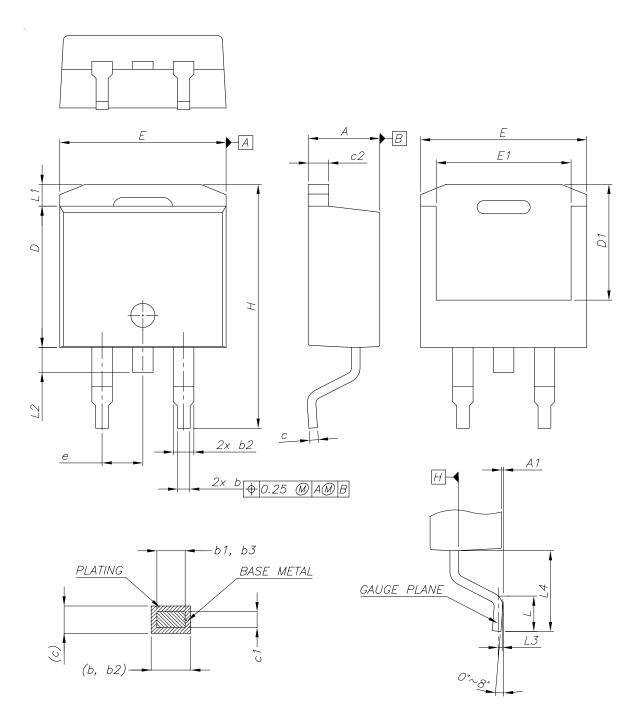
|      | Таре |      |        | Reel     |      |
|------|------|------|--------|----------|------|
| Dim. | n    | nm   | Dim.   | m        | m    |
| Dim. | Min. | Max. |        | Min.     | Max. |
| A0   | 10.5 | 10.7 | A      |          | 330  |
| B0   | 15.7 | 15.9 | В      | 1.5      |      |
| D    | 1.5  | 1.6  | С      | 12.8     | 13.2 |
| D1   | 1.59 | 1.61 | D      | 20.2     |      |
| E    | 1.65 | 1.85 | G      | 24.4     | 26.4 |
| F    | 11.4 | 11.6 | N      | 100      |      |
| K0   | 4.8  | 5.0  | Т      |          | 30.4 |
| P0   | 3.9  | 4.1  |        |          |      |
| P1   | 11.9 | 12.1 | Base   | quantity | 1000 |
| P2   | 1.9  | 2.1  | Bulk c | quantity | 1000 |
| R    | 50   |      |        |          |      |
| Т    | 0.25 | 0.35 |        |          |      |
| W    | 23.7 | 24.3 |        |          |      |



# 4.3 D<sup>2</sup>PAK (TO-263) type B package information

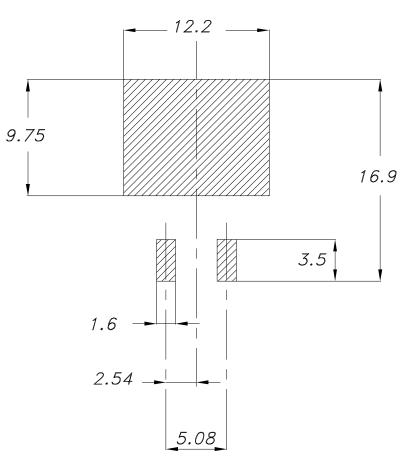
57

## Figure 20. D<sup>2</sup>PAK (TO-263) type B package outline



| Dim  |       | mm       |       |
|------|-------|----------|-------|
| Dim. | Min.  | Тур.     | Max.  |
| A    | 4.36  |          | 4.56  |
| A1   | 0     |          | 0.25  |
| b    | 0.70  |          | 0.90  |
| b1   | 0.51  |          | 0.89  |
| b2   | 1.17  |          | 1.37  |
| b3   | 1.36  |          | 1.46  |
| С    | 0.38  |          | 0.694 |
| c1   | 0.38  |          | 0.534 |
| c2   | 1.19  |          | 1.34  |
| D    | 8.60  |          | 9.00  |
| D1   | 6.90  |          | 7.50  |
| E    | 10.15 |          | 10.55 |
| E1   | 8.10  |          | 8.70  |
| e    |       | 2.54 BSC |       |
| Н    | 15.00 |          | 15.60 |
| L    | 1.90  |          | 2.50  |
| L1   |       |          | 1.65  |
| L2   |       |          | 1.78  |
| L3   |       | 0.25     |       |
| L4   | 4.78  |          | 5.28  |

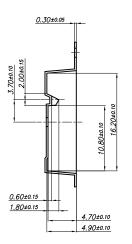
## Table 10. D<sup>2</sup>PAK (TO-263) type B mechanical data

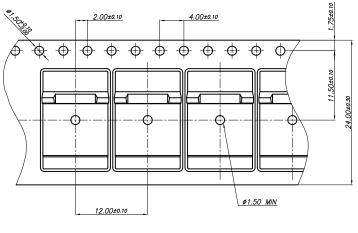


#### Figure 21. D<sup>2</sup>PAK (TO-263) recommended footprint (dimensions are in mm)

4.4 D<sup>2</sup>PAK type B packing information

## Figure 22. D<sup>2</sup>PAK type B tape outline



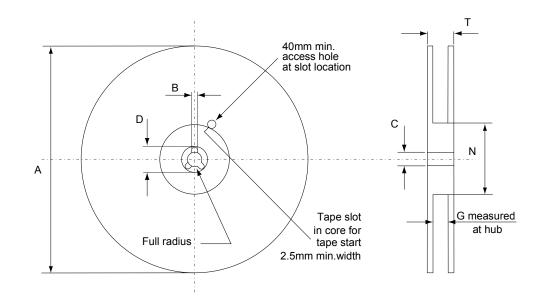




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Footprint





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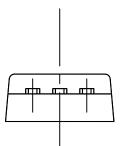
## Table 11. D<sup>2</sup>PAK type B reel mechanical data

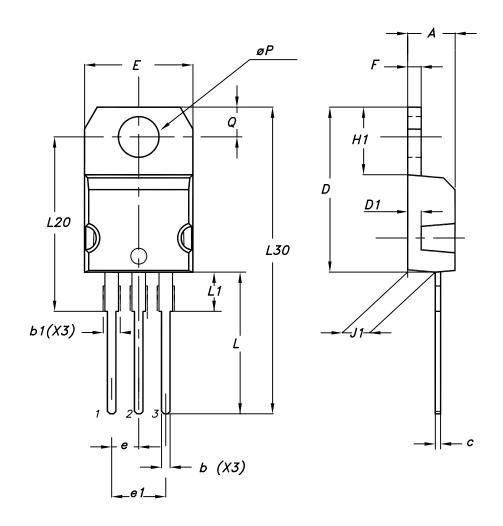
| Dim. | mm   |      |  |
|------|------|------|--|
|      | Min. | Max. |  |
| А    |      | 330  |  |
| В    | 1.5  |      |  |
| С    | 12.8 | 13.2 |  |
| D    | 20.2 |      |  |
| G    | 24.4 | 26.4 |  |
| Ν    | 100  |      |  |
| Т    |      | 30.4 |  |



# 4.5 TO-220 type A package information

Figure 24. TO-220 type A package outline





0015988\_typeA\_Rev\_21

| Dim. | mm    |       |       |  |
|------|-------|-------|-------|--|
| Dim. | Min.  | Тур.  | Max.  |  |
| A    | 4.40  |       | 4.60  |  |
| b    | 0.61  |       | 0.88  |  |
| b1   | 1.14  |       | 1.55  |  |
| С    | 0.48  |       | 0.70  |  |
| D    | 15.25 |       | 15.75 |  |
| D1   |       | 1.27  |       |  |
| E    | 10.00 |       | 10.40 |  |
| е    | 2.40  |       | 2.70  |  |
| e1   | 4.95  |       | 5.15  |  |
| F    | 1.23  |       | 1.32  |  |
| H1   | 6.20  |       | 6.60  |  |
| J1   | 2.40  |       | 2.72  |  |
| L    | 13.00 |       | 14.00 |  |
| L1   | 3.50  |       | 3.93  |  |
| L20  |       | 16.40 |       |  |
| L30  |       | 28.90 |       |  |
| øP   | 3.75  |       | 3.85  |  |
| Q    | 2.65  |       | 2.95  |  |

## Table 12. TO-220 type A package mechanical data

# **Revision history**

| Date        | Version | Changes   |
|-------------|---------|---|
| 09-Sep-2004 | 1       | First release   |
| 10-Jun-2005 | 2       | Typing error, wrong description   |
| 26-Jul-2006 | 3       | The document has been reformatted, no content change  |
| 31-Aug-2006 | 4       | Typo mistake on order code  |
| 21-Dec-2006 | 5       | Various changes on "Test conditions" for Table 5. and Table 6.  |
| 12-Jan-2007 | 6       | Order code has been corrected   |
| 01-Oct-2018 | 7       | The part numbers STB11NM60-1 and STP11NM60FP have been moved to a separate datasheet and the document has been updated accordingly. |
|             |         | Modified Table 1. Absolute maximum ratings, Table 2. Thermal data and Table 5. Dynamic.   |
|             |         | Modified Section 2.1 Electrical characteristics (curves).   |
|             |         | Updated Section 4 Package information.  |
|             |         | Minor text changes.   |

## Table 13. Document revision history



# Contents

| 1   | Elect                      | rical ratings  | 2  |  |  |
|-----|----------------------------|--|----|--|--|
| 2   | Electrical characteristics |  |    |  |  |
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| 3   | Test                       | circuits   | 7  |  |  |
| 4   | Pack                       | age information  | 8  |  |  |
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|     | 4.2                        | D <sup>2</sup> PAK packing information                 | 10 |  |  |
|     | 4.3                        | D <sup>2</sup> PAK (TO-263) type B package information | 12 |  |  |
|     | 4.4                        | D <sup>2</sup> PAK type B packing information          | 15 |  |  |
|     | 4.5                        | TO-220 type A package information                      | 16 |  |  |
| Rev | ision I                    | nistory  | 19 |  |  |



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